



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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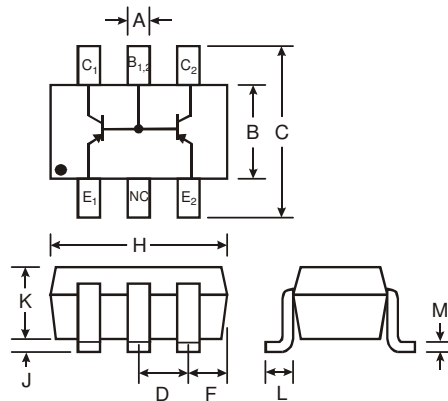


Features

- Epitaxial Planar Die Construction
- Intrinsically Matched PNP Pair (Note 1)
- Small Surface Mount Package
- 2% h_{FE} Matched Tolerance
- **Lead Free/RoHS Compliant (Note 3)**
- **"Green" Device (Note 4 and 5)**

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.015 grams (approximate)



| SOT-26 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 0.35 | 0.50 | 0.38 |
| B | 1.50 | 1.70 | 1.60 |
| C | 2.70 | 3.00 | 2.80 |
| D | — | — | 0.95 |
| F | — | — | 0.55 |
| H | 2.90 | 3.10 | 3.00 |
| J | 0.013 | 0.10 | 0.05 |
| K | 1.00 | 1.30 | 1.10 |
| L | 0.35 | 0.55 | 0.40 |
| M | 0.10 | 0.20 | 0.15 |
| All Dimensions in mm | | | |

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------------|---------------------------|
| Collector-Base Voltage | V_{CBO} | -40 | V |
| Collector-Emitter Voltage | V_{CEO} | -40 | V |
| Emitter-Base Voltage | V_{EBO} | -5.0 | V |
| Collector Current - Continuous | I_C | -200 | mA |
| Power Dissipation (Note 2) | P_d | 225 | mW |
| Thermal Resistance, Junction to Ambient (Note 2) | $R_{\theta JA}$ | 556 | $^\circ\text{C}/\text{W}$ |
| Operating and Storage Temperature Range | T_j, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

- Notes:
1. Built with adjacent die from a single wafer.
 2. Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. No purposefully added lead.
 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 5. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

Electrical Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|--------------------------------------|----------------------|-------|----------------|--------------------|---|
| OFF CHARACTERISTICS (Note 6) | | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | -40 | — | V | I _C = -10μA, I _E = 0 |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | -40 | — | V | I _C = -1.0mA, I _B = 0 |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | -5.0 | — | V | I _E = -10μA, I _C = 0 |
| Collector Cutoff Current | I _{CEX} | — | -50 | nA | V _{CE} = -30V, V _{EB(OFF)} = -3.0V |
| Base Cutoff Current | I _{BL} | — | -50 | nA | V _{CE} = -30V, V _{EB(OFF)} = -3.0V |
| ON CHARACTERISTICS (Note 6) | | | | | |
| DC Current Gain (Note 7) | h _{FE} | 60 | — | — | I _C = -100μA, V _{CE} = -1.0V |
| | | 80 | — | | I _C = -1.0mA, V _{CE} = -1.0V |
| | | 100 | 300 | | I _C = -10mA, V _{CE} = -1.0V |
| | | 60 | — | | I _C = -50mA, V _{CE} = -1.0V |
| | | 30 | — | | I _C = -100mA, V _{CE} = -1.0V |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | — | -0.25 -0.40 | V | I _C = -10mA, I _B = -1.0mA I _C = -50mA, I _B = -5.0mA |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | -0.65 | -0.85 -0.95 | V | I _C = -10mA, I _B = -1.0mA I _C = -50mA, I _B = -5.0mA |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C _{obo} | — | 4.5 | pF | V _{CB} = -5.0V, f = 1.0MHz, I _E = 0 |
| Input Capacitance | C _{ibo} | — | 10 | pF | V _{EB} = -0.5V, f = 1.0MHz, I _C = 0 |
| Input Impedance | h _{ie} | 2.0 | 12 | kΩ | V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz |
| Voltage Feedback Ratio | h _{re} | 0.1 | 10 | x 10 ⁻⁴ | |
| Small Signal Current Gain | h _{fe} | 100 | 400 | — | |
| Output Admittance | h _{oe} | 3.0 | 60 | μS | |
| Current Gain-Bandwidth Product | f _T | 250 | — | MHz | |
| Noise Figure | NF | — | 4.0 | dB | V _{CE} = -5.0V, I _C = -100μA, R _S = 1.0kΩ, f = 1.0kHz |
| SWITCHING CHARACTERISTICS | | | | | |
| Delay Time | t _d | — | 35 | ns | V _{CC} = -3.0V, I _C = -10mA, V _{BE(off)} = 0.5V, I _{B1} = -1.0mA |
| Rise Time | t _r | — | 35 | ns | |
| Storage Time | t _s | — | 225 | ns | V _{CC} = -3.0V, I _C = -10mA, I _{B1} = I _{B2} = -1.0mA |
| Fall Time | t _f | — | 75 | ns | |

- Notes: 6. Short duration pulse test used to minimize self-heating effect.
7. The DC current gain, h_{FE}, is matched at I_C = -10mA and V_{CE} = -1.0V with typical matched tolerances of 1% and maximum of 2%.

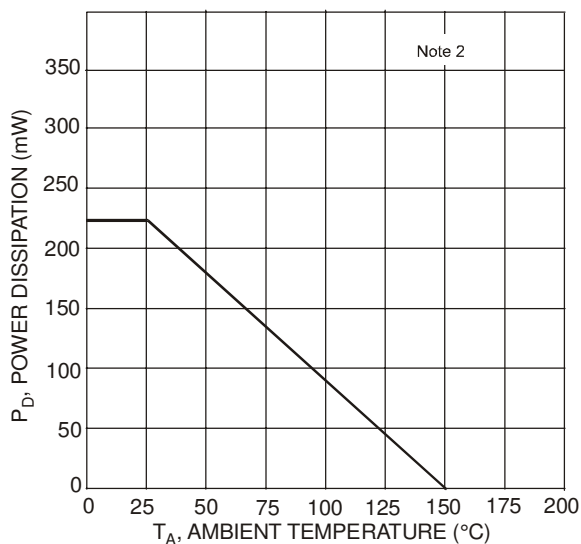


Fig. 1, Max Power Dissipation vs. Ambient Temperature, Total Device

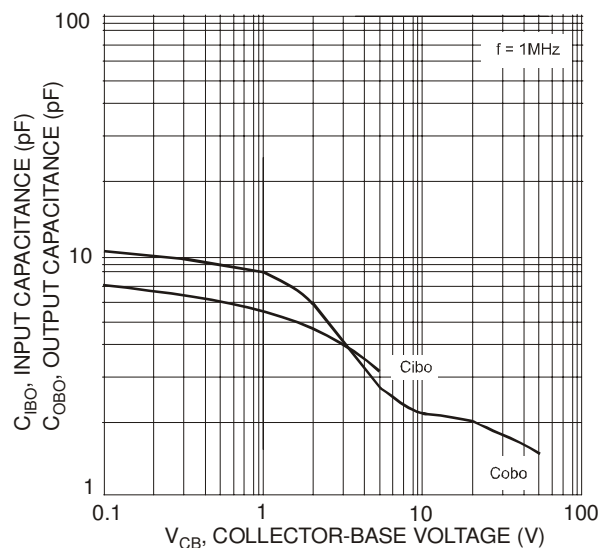


Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage

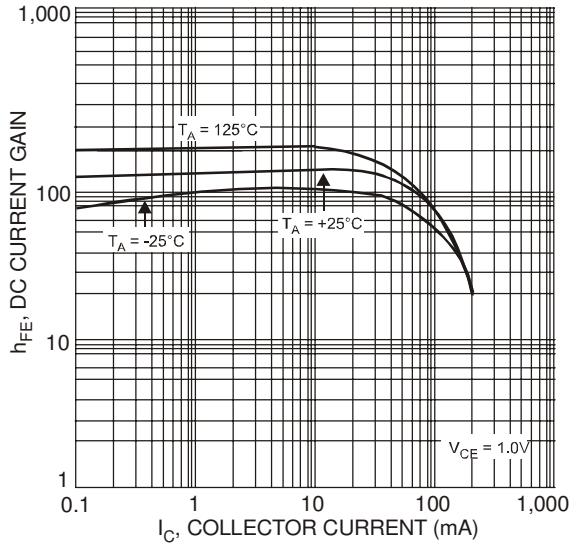


Fig. 3, Typical DC Current Gain vs. Collector Current

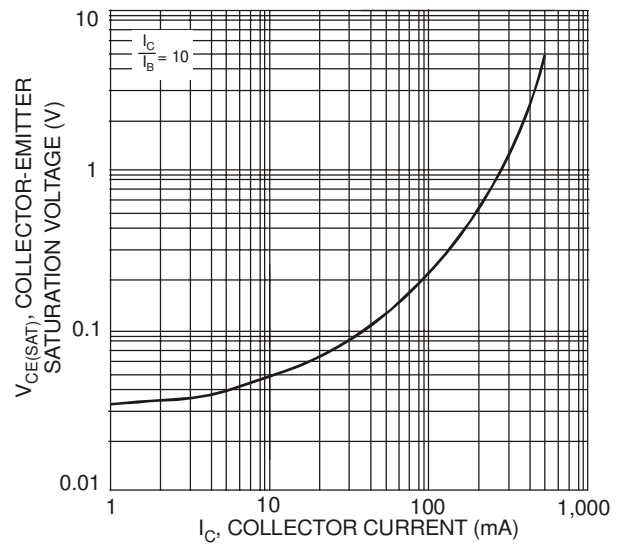


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

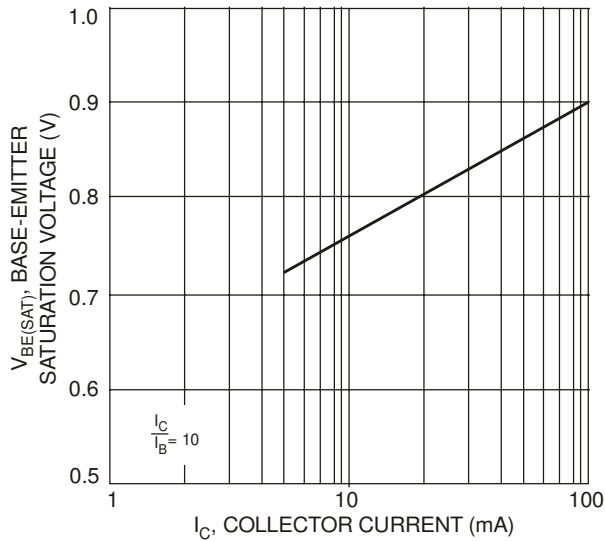


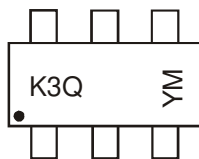
Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current

Ordering Information (Note 5 & 8)

| Device | Packaging | Shipping |
|--------------|-----------|------------------|
| DMMT3906-7-F | SOT-26 | 3000/Tape & Reel |

Notes: 8. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



K3Q = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: T = 2006
 M = Month ex: 9 = September

Date Code Key

| Year | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
|------|------|------|------|------|------|------|------|------|------|
| Code | R | S | T | U | V | W | X | Y | Z |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

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